

Polar™ **Power MOSFET**

Symbol

V_{DSS}

RV

IXTA10N60P IXTP10N60P

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Rectifier

Test Conditions

T₁ = 25°C to 150°C



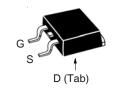
= 600V10A ≤ **740**mΩ



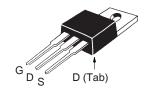
Maximum Ratings

600

TO-263 AA (IXTA)



TO-220AB (IXTP)



G = Gate D = Drain S = Source Tab = Drain

V _{DGR}	$T_J = 25^{\circ}C$ to 150°C, $R_{GS} = 1M\Omega$	600	V
V _{GSS}	Continuous	±30	V
\mathbf{V}_{GSM}	Transient	±40	V
I _{D25}	$T_{c} = 25^{\circ}C$	10	Α
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	25	Α
I _A	$T_{c} = 25^{\circ}C$	10	Α
E _{AS}	$T_{c} = 25^{\circ}C$	500	mJ
dv/dt	$I_{_{\mathrm{S}}} \le I_{_{\mathrm{DM}}}, V_{_{\mathrm{DD}}} \le V_{_{\mathrm{DSS}}}, T_{_{\mathrm{J}}} \le 150^{\circ}\mathrm{C}$	10	V/ns
P_{D}	T _c = 25°C	200	W
T _J		-55 +150	°C
T_{JM}		150	°C
T _{stg}		-55 +150	°C
T _L	1.6mm (0.062in.) from Case for 10s	300	°C
T _{sold}	Plastic Body for 10 Seconds	260	°C
\mathbf{M}_{d}	Mounting Torque (TO-220)	1.13 / 10	Nm/lb.in.
Weight	TO-263 TO-220	2.5 3.0	g g

Features

- International Standard Packages
- Dynamic dv/dt Rating
- Avalanche Rated
- Fast Intrinsic Rectifier
- Low Q_G
- Low R_{DS(on)}
- Low Drain-to-Tab Capacitance
- Low Package Inductance

Symbol Test Conditions Characteristic Values (T₁ = 25°C Unless Otherwise Specified) Min. Typ. Max.

600

DSS	V _{GS} = 0 V, I _D = 200μ/λ	000		
V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250\mu A$	3.0	5.5	V
I _{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$		±100	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$		5	μΑ
	$T_{J} = 1$	125°C	50	μΑ
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, \text{ Notes 1, } $	2	740	$m\Omega$

Advantages

- Easy to Mount
- Space Savings

Applications

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode **Power Supplies**
- Uninterrupted Power Supplies
- AC Motor Drives
- High Speed Power Switching Applications

 $V = 0V I = 250 \mu A$



•			acteristic Values		
$(T_J = 2)$	5°C, l	Jnless Otherwise Specified)	Min.	Тур.	Max.
g_{fs}		$V_{DS} = 10V, I_{D} = 0.5 \bullet I_{D25}, \text{ Note 1}$	6	11	S
C _{iss})			1720	pF
C_{oss}	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		160	pF
C _{rss}	J			14	pF
t _{d(on)}	١	Resistive Switching Time		23	ns
t _r		$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		27	ns
t _{d(off)}		$R_{\rm G} = 10\Omega$ (External)		65	ns
t _f)			21	ns
$\mathbf{Q}_{g(on)}$)			32	nC
Q _{gs}	}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$		12	nC
\mathbf{Q}_{gd}	J			10	nC
R _{thJC}					0.62 °C/W
R _{thCH}		TO-220		0.50	°C/W

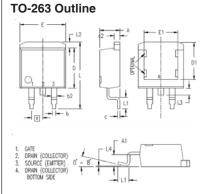
Source-Drain Diode

SymbolTest ConditionsChara $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		acteristic Values Typ. Max.			
I _s	$V_{GS} = 0V$			10	Α
I _{SM}	Repetitive, Pulse Width Limited by $\mathrm{T}_{_{\mathrm{JM}}}$			30	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.5	V
t _{rr}	$I_{_{ m F}} = 10 { m A}, \ { m V}_{_{ m GS}} = 0 { m V}$ -di/dt = 100A/ μ s, ${ m V}_{_{ m R}} = 100 { m V}$		500		ns

Notes: 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

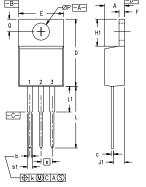
2. On through-hole packages, $R_{DS(on)}$ Kelvin test contact location must be 5mm or less from the package body.

IXTP10N60P



MYZ	INCHES MILLIME		ETERS	
2114	MIN	MAX	MIN	MAX
Α	.160	.190	4.06	4.83
A1	.080	.110	2.03	2.79
b	.020	.039	0.51	0.99
b2	.045	.055	1.14	1.40
С	.016	.029	0.40	0.74
c2	.045	.055	1.14	1.40
D	.340	.380	8.64	9.65
D1	.315	.350	8.00	8.89
Ε	.380	.410	9.65	10.41
E1	.245	.320	6.22	8.13
е	.100 BSC		2.54 BSC	
L	.575	.625	14.61	15.88
L1	.090	.110	2.29	2.79
L2	.040	.055	1.02	1.40
L3	.050	.070	1.27	1.78
L4	0	.005	0	0.13



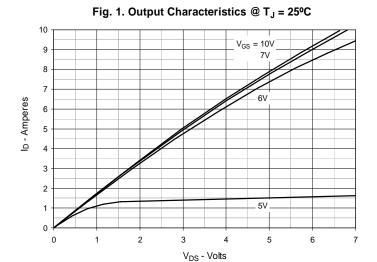


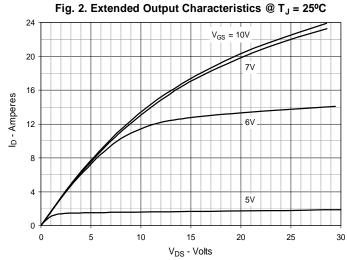
Pins: 1 - Gate 2 - Drain 3 - Source

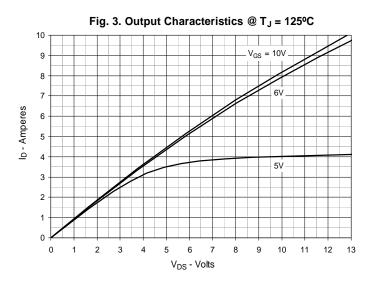
MYZ	INCHES		MILLIMETERS		
3111	MIN	MAX	MIN	MAX	
Α	.170	.190	4.32	4.83	
b	.025	.040	0.64	1.02	
b1	.045	.065	1.15	1.65	
С	.014	.022	0.35	0.56	
D	.580	.630	14.73	16.00	
E	.390	.420	9.91	10.66	
е	.100 BSC		2.54 BSC		
F	.045	.055	1.14	1.40	
H1	.230	.270	5.85	6.85	
J1	.090	.110	2.29	2.79	
k	0	.015	0	0.38	
L	.500	.550	12.70	13.97	
L1	.110	.230	2.79	5.84	
ØР	.139	.161	3.53	4.08	
Q	.100	.125	2.54	3.18	

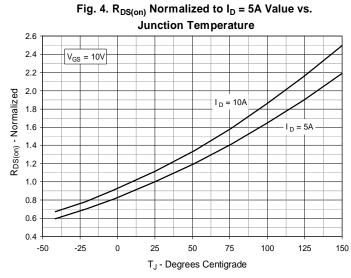
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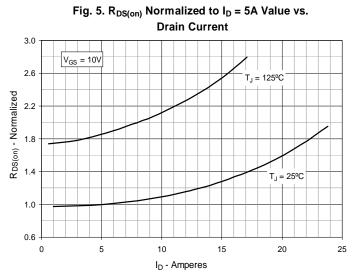


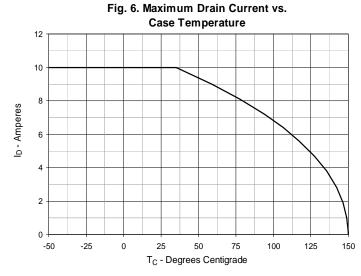




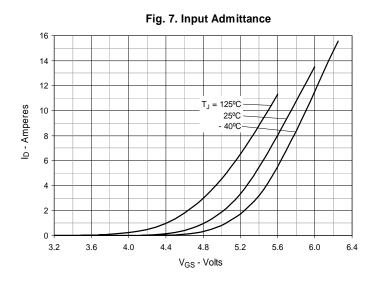


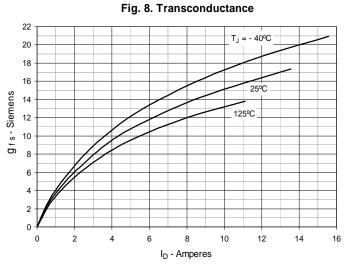


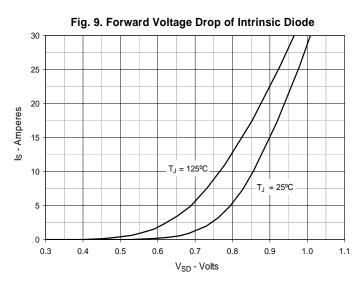


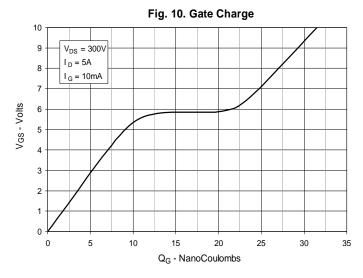


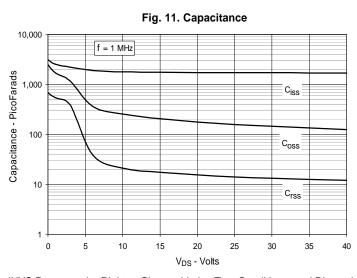


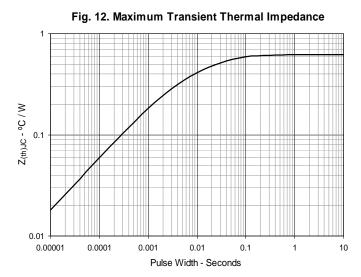












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